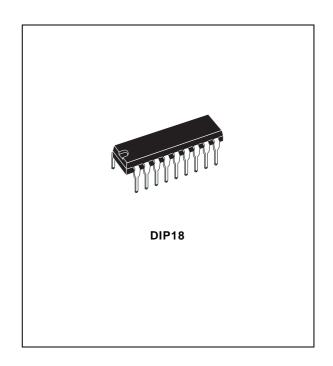


EIGHT DARLINGTON ARRAYS

- EIGHT DARLINGTONS WITH COMMON EMIT-TERS
- OUTPUT CURRENT TO 500 mA
- OUTPUT VOLTAGE TO 50 V
- INTEGRAL SUPPRESSION DIODES
- VERSIONS FOR ALL POPULAR LOGIC FAMI-LIES
- OUTPUT CAN BE PARALLELED
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY BOARD LAYOUT



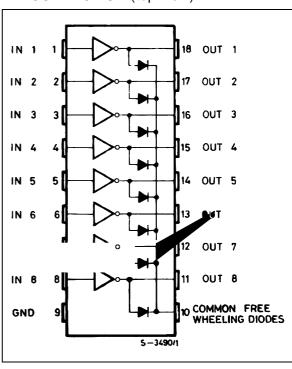
DESCRIPTION

The ULN2801A-ULN2805A each contain eight darlington transistors with common emitters and integral suppression diodes for inductive loads. Each darlington features a peak load current rating of 600mA (500mA continuous) and can withstand at least 50V in the off state. Outputs may be paralleled for higher current capability.

Five versions are available to simplify interfacing to standard logic families : the ULN2801A is designed for general purpose applications with a current limit resistor ; the ULN2802A has a 10.5k Ω input resistor and zener for 14-25V PMOS ; the ULN2803A has a 2.7k Ω input resistor for 5V TTL and CMOS ; the ULN2804A has a 10.5k Ω input resistor for 6-15V CMOS and the ULN2805A is designed to sink a minimum of 350mA for standard and Schottky TTL where higher output current is required.

All types are supplied in a 18-lead plastic DIP with a copper lead from and feature the convenient input-opposite-output pinout to simplify board layout.

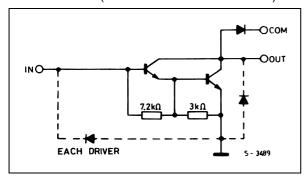
PIN CONNECTION (top view)

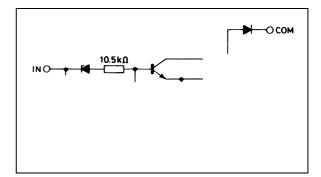


September 2003

SCHEMATIC DIAGRAM AND ORDER CODES

For ULN2801A (each driver for PMOS-CMOS)





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
Vo	Output Voltage	50	V	
Vi	Input Voltage for ULN2802A, UL2803A, ULN2804A for ULN2805A	30 15	V	
Ic	Continuous Collector Current	500	mA	
I _B	Continuous Base Current	25	mA	
P _{tot}	Power Dissipation (one Darlington pair) (total package)	1.0 2.25	V	
T _{amb}	Operating Ambient Temperature Range	- 20 to 85	°C	
T _{stg}	Storage Temperature Range	- 55 to 150	°C	
Tj	Junction Temperature Range	- 20 to 150	°C	

THERMAL DATA

	Symbol	Parameter	Value	Unit
ſ	R _{th j-amb}	Thermal Resistance Junction-ambient Max.	55	°C/W

ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	Fig.
Icex	Output Leakage Current	V _{CE} = 50V T _{amb} = 70°C, V _{CE} = 50V T _{amb} = 70°C for ULN2802A V _{CE} = 50V, V _i = 6V for ULN2804A			50 100 500	μΑ μΑ μΑ	1a 1a 1b
		$V_{CE} = 50V, V_i = 1V$			500	μΑ	1b
V _{CE(sat)}	Collector-emitter Saturation Voltage	$I_{C} = 100$ mA, $I_{B} = 250$ μ A $I_{C} = 200$ mA, $I_{B} = 350$ μ A $I_{C} = 350$ mA, $I_{B} = 500$ μ A		0.9 1.1 1.3	1.1 1.3 1.6	V V	2
I _{i(on)}	Input Current	$ \begin{cases} \text{for ULN2802A} & V_i = 17V \\ \text{for ULN2803A} & V_i = 3.85V \\ \text{for ULN2804A} & V_i = 5V \\ & V_i = 12V \\ \text{for ULN2805A} & V_i = 3V \\ \end{cases} $		0.82 0.93 0.35 1 1.5	1.25 1.35 0.5 1.45 2.4	mA mA mA mA	3
I _{i(off)}	Input Current	$T_{amb} = 70^{\circ}C, I_{C} = 500\mu A$	50	65		μΑ	4
V _{i(on)}	Input Voltage	$\begin{array}{c} V_{CE} = 2 \ V \\ \text{for ULN2802A} \\ I_{C} = 300 \text{mA} \\ \text{for ULN2803A} \\ I_{C} = 200 \text{mA} \\ I_{C} = 250 \text{mA} \\ I_{C} = 300 \text{mA} \\ \text{for ULN2804A} \\ I_{C} = 125 \text{mA} \\ I_{C} = 200 \text{mA} \\ I_{C} = 275 \text{mA} \\ I_{C} = 350 \text{mA} \\ \text{for ULN2805A} \\ I_{C} = 350 \text{mA} \\ \end{array}$			13 2.4 2.7 3 5 6 7 8 2.4	V V V V V V V	5
h _{FE}	DC Forward Current Gain	for ULN2801A $V_{CE} = 2V, I_{C} = 350mA$	1000			_	2
Ci	Input Capacitance			15	25	pF	_
t _{PLH}	Turn-on Delay Time	0.5 V _i to 0.5 V _o		0.25	1	μs	_
t _{PHL}	Turn-off Delay Time	0.5 V _i to 0.5 V _o		0.25	1	μs	_
I _R	Clamp Diode Leakage Current	$V_R = 50V$ $T_{amb} = 70^{\circ}C, V_R = 50V$			50 100	μA μA	6 6
V_{F}	Clamp Diode Forward Voltage	I _F = 350mA		1.7	2	V	7



TEST CIRCUITS

Figure 1a.

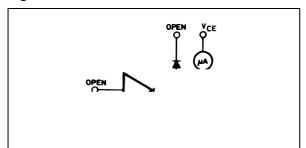


Figure 1b.



Figure 8 : Collector Current as a Function of Saturation Voltage.

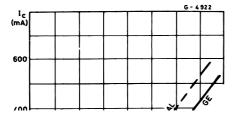
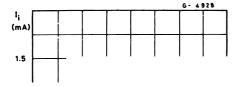
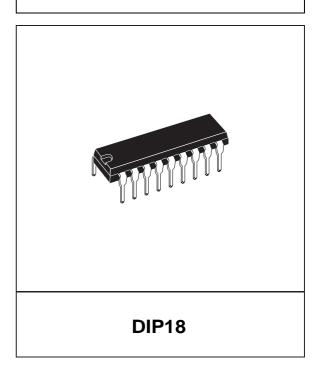


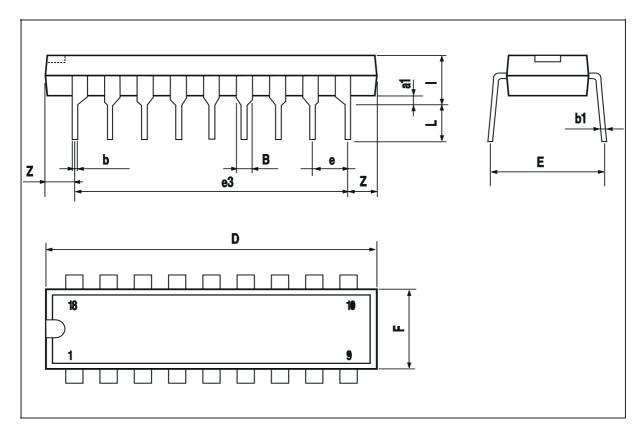
Figure 14 : Input Current as a Function of Input Voltage (for ULN2804A)



DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
a1	0.254			0.010			
В	1.39		1.65	0.055		0.065	
b		0.46			0.018		
b1		0.25			0.010		
D			23.24			0.915	
Е		8.5			0.335		
е		2.54			0.100		
e3		20.32			0.800		
F			7.1			0.280	
ı			3.93			0.155	
L		3.3			0.130		
Z		1.27	1.59		0.050	0.063	

OUTLINE AND MECHANICAL DATA





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